DESCRIPTION

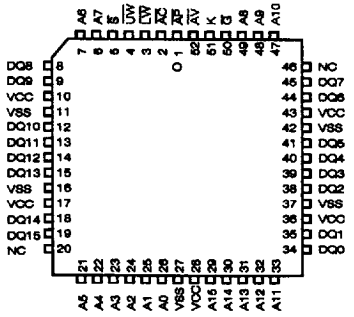
This device integrates high-speed 64Kx16 SRAM core, address registers, data input registers, a 2-bit burst address counter and pipelined output. All synchronous inputs pass through registers controlled by a positive-edge triggered clock(K).

The device is ideally suited for 486/Pentium system by including all necessary timing and control logic on a chip. Any external address latches, counters, or other timing and control logic are not necessary.

FEATURES

- **Single 3.3V±5% power supply.**
- **7ns/12ns/17ns access times from clock Support up to 67MHz System Operation**
- **Optimized for use with Intel 486/Pentium secondary cache applications (Interleaved burst sequence and Linear burst sequence)**
- **Registered data-out for pipelined read**
- **Byte writable using seperate upper/lower byte write input controls**
- **Write pass-through functionality**
- **On-chip burst address counter**
- **On-chip clocked input and output registers**
- **3-state buffered output with asynchronous output enable control**
- **Standard 52-lead PLCC package with JEDEC pinout**

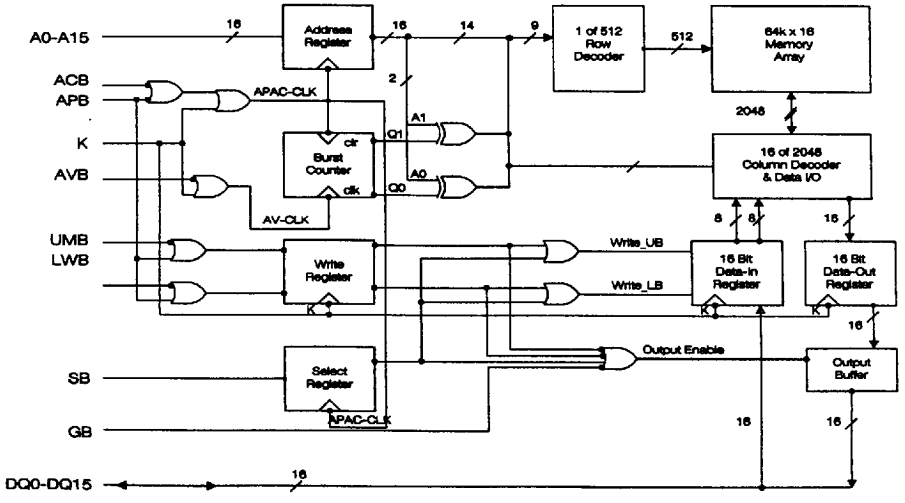
PIN CONNECTION



PART NUMBER EXAMPLES

Part NO.	Burst Sequence
HY67V16100	Interleaved
HY67V16101	Linear

FUNCTION BLOCK DIAGRAM



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PIN DESCRIPTIONS

SYMBOL	PIN NUMBER	TYPE	DESCRIPTION
K	51	Input	Clock. This signal is used to synchronize the device with the system timing. It registers the Addresses, Data inputs, Byte Write Enables and Chip Enable. It may clear or increment the burst counter depending on the state of APB, ACB and AVB.
A0-An	6, 7, 21, 22, 23, 24, 25, 26, 29, 30, 31, 32, 33, 47, 48, 49	Input	Synchronous Address. The addresses are registered at rising edge of the clock.
SB	5	Input	Chip Select. A synchronous control input used to enable(LOW state) and disable(HIGH state) the device. This input is sampled and registered only when a new base address cycle is initiated.
UWB/ LWB	3, 4	Input	Upper and Lower Byte Write Enable. Synchronous control input registered by rising edge of the clock. A LOW state allows data to be written into the device, and a HIGH state initiates a read cycle. UWB controls upper byte(DQ8-15) and LWB controls lower byte(DQ0-7).
APB	1	Input	Address Status from Processor. A synchronous control input registered by rising edge of the clock. A LOW state interrupts the burst sequence and loads in a new address. The devidce will read out the data at new address. This input over-rides ACB and UWB/LWB.
ACB	2	Input	Address Status from Cache Controller. A synchronous control input registered by rising edge of the clock. When this input is at LOW state and APB is HIGH state, burst sequence is interrupted and new addresses are loaded into the device. The device will perform a read or write cycle with new addresses.
AVB	52	Input	Burst Address Advance. A synchronous control input registered by rising edge of the clock. When this input is at LOW state, the burst counter increments at rising clock edge. A HIGH state will insert wait states into the burst sequence. The burst addresses will wrap around to the initial state after burst counter completed a burst sequence.
GB	50	Input	Output Enable. An asynchronous control input. A LOW state will enable the DQs and a HIGH state will tri-state the DQs.
DQ0-n	8, 9, 12, 13, 14, 15, 18, 19, 34, 35, 38, 39, 40, 41, 44, 45	Input/ Output	Data Input/Outputs. A bi-directional common I/O data pins. GB controls the pins when the device is outputting the data(read cycle) . At write cycle, input data are registered at rising edge of the clock.
Vcc	28	Supply	Positive Power Supply:+3.3V±5%
Vss	27	Supply	Negative Power Supply and Ground Return.
VccQ	10, 17, 36, 43	Supply	Isolated Output Buffer Supply:+3.3V±5%
VssQ	11, 16, 37, 42	Supply	Isolated Output Buffer Ground:GND
NC	20, 46	Supply	No Connection

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TRUTH TABLE

OPERATION	ADD.	SB	LWB	UWB	APB	ACB	AVB	K	GB	DQ
Deselected, Outputs High Z	X	H	X	X	X	L	X	L-H	X	Hi-Z
Output Disabled, Outputs High Z	X	X	X	X	X	X	X	X	H	Hi-Z
Register New Base Address, Read from Base Address During Next Cycle	NBA	L	X	X	L	X	X	L-H	L	VQ
Register New Base Address, Read from Base Address During Next Cycle	NBA	L	H	H	H	L	X	L-H	L	VQ
Increment Burst Address, Read from Incremented Address During Next Cycle	X	X	H	H	H	H	L	L-H	L	VQ
Read, Non-Incremented Burst Address : Wait-State	X	X	H	H	H	H	H	L-H	L	VQ
Register New Base Address, Write Both Bytes at Base Address	NBA	L	L	L	H	L	X	L-H	X	VD
Register New Base Address, Write Only the Lower Byte at Base Address	NBA	L	L	H	H	L	X	L-H	X	VD
Register New Base Address, Write Only the Upper Byte at Base Address	NBA	L	H	L	H	L	X	L-H	X	VD
Increment Burst Address, Write Both Bytes at Incremented Address	X	X	L	L	H	H	L	L-H	X	VD
Increment Burst Address, Write Only Lower Byte at Incremented Address	X	X	L	H	H	H	L	L-H	X	VD
Increment Burst Address, Write Only Upper Byte at Incremented Address	X	X	H	L	H	H	L	L-H	X	VD
Write Both Bytes, Non-Incremented Burst Address : Wait-State	X	X	L	L	H	H	H	L-H	X	VD
Lower Byte Write, Non-Incremented Burst Address : Wait-State	X	X	L	H	H	H	H	L-H	X	VD
Upper Byte Write, Non-Incremented Burst Address : Wait-State	X	X	H	L	H	H	H	L-H	X	VD

Note :
All inputs except GB must meet set-up and hold times on the rising edge(LOW to HIGH) of K. The burst counter is cleared or incremented by the rising edge of K combined with the control inputs APB, ACB and AVB.

Hi-Z = High Impedance
VQ = Valid Data Output
VD = Valid Data Input
NBA = New Base Address

X = Don't Care : Input
Changing : Output
L = Low
H = High

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INTERLEAVED BURST SEQUENCE TABLE

Note that in every case the sequence starts with the initial address, then complements the RAM LSB, then complements both, and finally complements the RAM 2nd LSB, It is only when application-specific address weights are assigned that the sequence appears to differ.

APPLICATION TYPE	SEQUENCE 0	SEQUENCE 1	SEQUENCE 2	SEQUENCE 3
'486 Application :				
Initial	00	04	08	0C
First in Burst	04	00	0C	08
Second in Burst	08	0C	00	04
Third in Burst	0C	08	04	00
Pentium Application :				
Initial	00	08	10	18
First in Burst	08	00	18	10
Second in Burst	10	18	00	08
Third in Burst	18	10	08	00
Arbitrary Application :				
Initial	RAM A1 A0	RAM A1 A0	RAM A1 A0	RAM A1 A0
First in Burst	RAM A1 A0B	RAM A1 A0B	RAM A1 A0B	RAM A1 A0B
Second in Burst	RAM A1B A0	RAM A1B A0	RAM A1B A0	RAM A1B A0
Third in Burst	RAM A1B A0B	RAM A1B A0B	RAM A1B A0B	RAM A1B A0B

LINEAR BURST SEQUENCE TABLE

	SEQUENCE 0	SEQUENCE 1	SEQUENCE 2	SEQUENCE 3
Initial	RAM A1B A0B	RAM A1B A0	RAM A1 A0B	RAM A1 A0B
First in Burst	RAM A1B A0	RAM A1 A0B	RAM A1 A0	RAM A1B A0B
Second in Burst	RAM A1 A0B	RAM A1 A0	RAM A1B A0B	RAM A1B A0
Third in Burst	RAM A1 A0	RAM A1B A0B	RAM A1B A0	RAM A1 A0B

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ABSOLUTE MAXIMUM RATINGS

Stress greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in the excess of those given in the operation sections of this data sheet. Exposure to Absolute Maximum Ratings for extended periods can adversely affect device reliability.

Parameter	SYMBOL	MIN	MAX	UNIT
Storage Temperature	TSTG	-55	125	°C
Junction Temperature	TC	···	125	°C
Case Temperature Under Bias	···	-10	85	°C
VCC Potential to VSS	···	-0.5	4.6	V
Input Voltage(dc)	···	-0.3	VCC+0.3	V

RECOMMENDED OPERATING CONDITIONS

Recommended Operating Conditions are defined as the range of operating conditions over which the device performance meets or exceeds the specified DC characteristics.

PARAMETER	SYMBOL	MIN	MAX	UNIT
Operating Supply	VCC	3.1	3.5	V
Supply Return, Reference Level	VSS	0.0	0.0	V
Input Low Voltage Level	VIL	-0.3	0.8	V
Input High Voltage Level	VIH	2.0	VCC+0.3	V
Case Temperature	TC	0	70	°C

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ELECTRICAL CHARACTERISTIC

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Input Voltage : High Low	VIH VIL	··· ···		2.0 -0.3	··· ···	Vcc+0. 30.8	V V
Output Voltage : High Low	VOH VOL	IOH=-4.0mA IOL=8.0mA		2.4 ···	··· ···	··· 0.4	V V
Input Leakage Current	IL1	0V≤VIN≤Vcc		-2	···	2	uA
Output Leakage Current	IL0	GB≥Vcc-0.2, 0V≤VOUT≤Vcc		-2	···	2	uA
Power Supply Current: Operating	Icc	Device selected, all inputs≤VIL or ≥VIH, Vcc=MAX, Tcyc≥tKC min, outputs open.	15ns	···	···	170	mA
			20ns	···	···	120	mA
			25ns	···	···	80	mA
CMOS Standby	Isb1	Device deselected ; $\overline{S}$≥Vcc-0.2, $\overline{AC}$≤Vss+0.2, all inputs ≤Vss+0.2 or ≥Vcc-0.2, all inputs static, Vcc=MAX, fCLK=0.		···	···	2	mA
	Isb2	Device deselected ; $\overline{S}$≥Vcc-0.2, $\overline{AC}$≤Vss+0.2, all inputs ≤Vss+0.2 or ≥ Vcc-0.2, all inputs static, Vcc=MAX, cycle time≥tKC min.		···	···	60	mA
	Isb3	Device deselected; $\overline{S}$≥VIH, $\overline{AC}$≤VIL, all inputs ≤VIL or ≥VIH, all inputs static, Vcc=MAX, fCLK=0.		···	···	8	mA
Short Ciruit Output Current	Ios	-		···	···	35	mA

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TIMING CHARACTERISTICS

SYMBOL	'486/'P5 Local Bus Rate	40MHz		50MHz		67MHz		Unit
	Cache RAM	17ns		12ns		7ns		
	Parameter	Min	Max	Min	Max	Min	Max	
tCYC	Cycle Time	25	···	20	···	15	···	ns
tKQV	Access Time from Clock	···	17	···	12	···	7	ns
tIS tAS tSS tAPS tACS tAVS tWS tDS	Input Setup Time Address Select Address Status - μP Address Status - Controller Address Advance Write Enables(LWB, UWB) Data In	3	···	2.0	···	2.0	···	ns
tIH tAH tSH tAPH tACH tAVH tWH tDH	Input Hold Time Address Select Address Status - μP Address Status - Controller Address Advance Write Enables (LWB, UWB) Data In	3	···	2.0	···	2.0	···	ns
tKH	Clock High Pulse Width	8	···	6	···	4.5	···	ns
tKL	Clock Low Pulse Width	8	···	6	···	4.5	···	ns
tGLQX	Output Enable to Output Active	3	···	2	···	1	···	ns
tGLQV	Output Enable Time	···	7	···	6	···	6	ns
tGHQZ	Output Disable Time	···	7	···	6	···	6	ns
tKQX	Output Change from Clock & Output Enable from Clock	4	···	3	···	3	···	ns
tKQZ	Output Disable from Clock	···	10	···	8	···	7	ns

NOTE :
1. Switching measurements are from 1.5V levels on the inputs to 1.5V levels on the outputs, except for enable and disable times.
2. Enable and disable time measurements are from 1.5V levels on the inputs to change of 0.1V in the output levels.
3. See figure AC TEST LOAD A. for output load.
4. Input levels for switching measurements are 0V to 3.0V.
5. Input rise and fall times for switching measurements are ≤2.0ns(20% to 80%).
6. This unit is measured using output loading as specified in figure AC TEST LOAD B.

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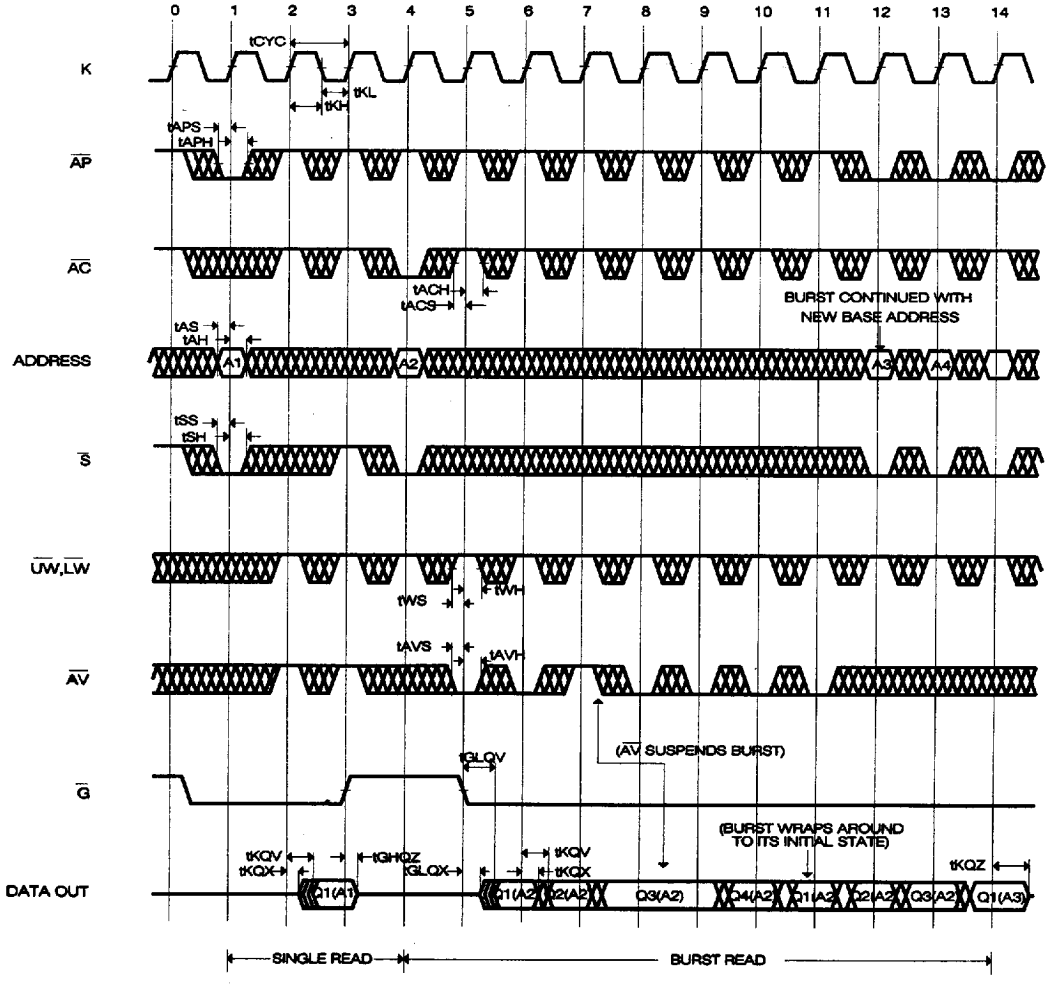
TIMNING DIAGRAM

READ CYCLE



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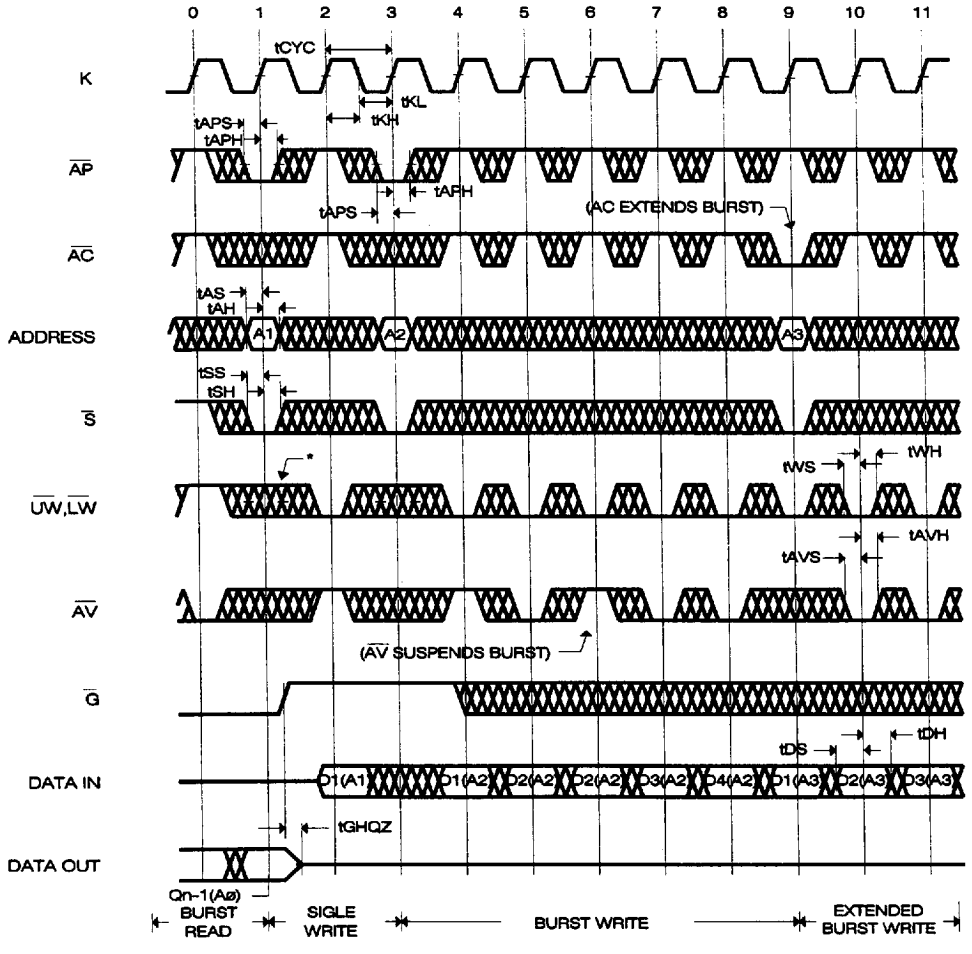
WRITE CYCLE



* When $\overline{AP}$ is initiates the burst sequence, the $\overline{W}$ control input is ignored for the first cycle, The $\overline{W}$ and DATA IN should be asserted and registered in the subsequent cycle.

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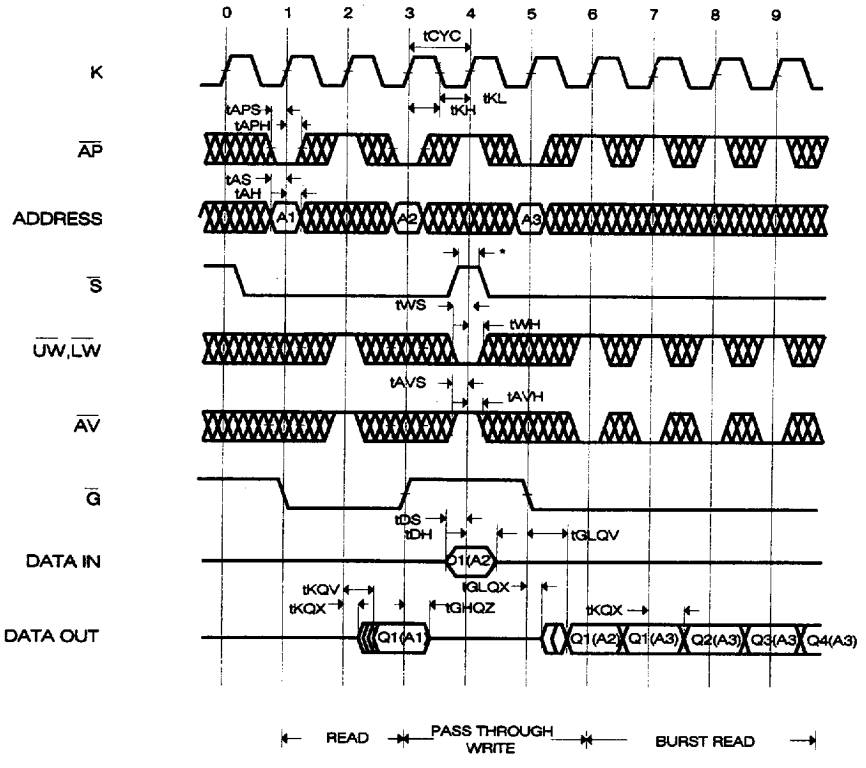
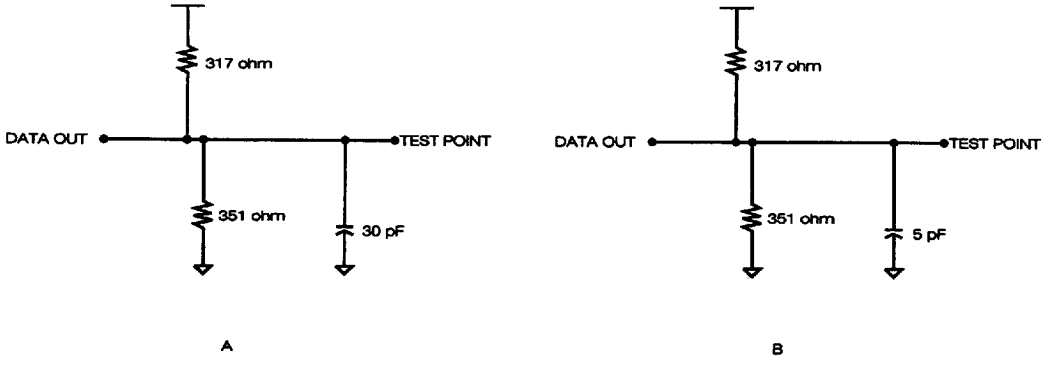
READ AND WRITE



*The state of $\overline{S}$ at 4 is ignored due to address A2 being registered one cycle earlier.

AC TEST LOAD



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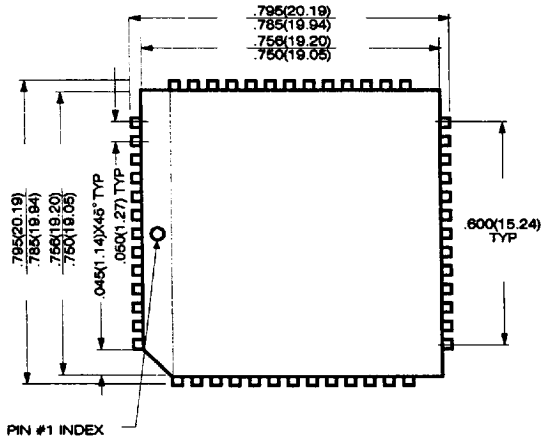
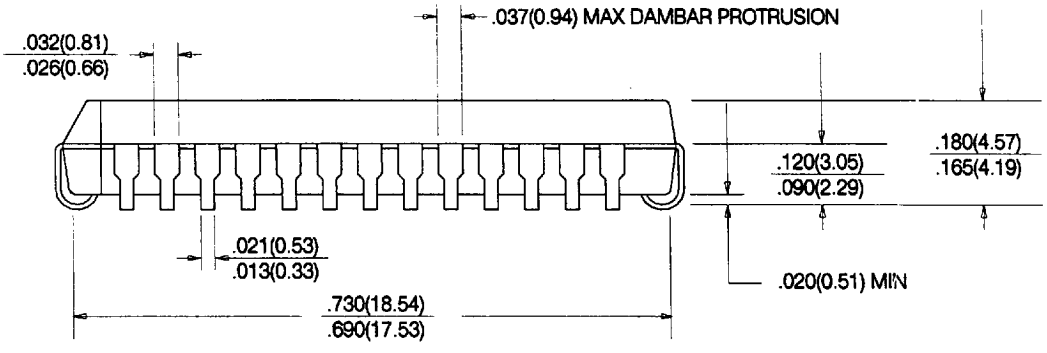
PACKAGE INFORMATION





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ORDERING INFORMATION

PART NO.	SPEED(ns)	FEATURES	PACKAGE
HY67V16100C	7/12/17	Pipelined (Interleaved)	52pin PLCC
HY67V16101C	7/12/17	Pipelined (Linear)	52pin PLCC

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